

Europass Curriculum Vitae

Personal information

Surname(s) / First name(s)

Address(es)

Telephone(s) Fax(es)

E-mail

Nationality

Date of birth

Gender

Desired employment / Occupational field

Work experience

Dates

Dates

Dates

March 2011 - onwards General Director

Marian Enachescu

Romanian

male

Main activities and responsibilities

Name and address of employer

Type of business or sector

Occupation or position held

March 2009 - May 2010

Occupation or position held

Main activities and responsibilities

Name and address of employer

Type of business or sector

Occupation or position held

Deputy Secretary of State and Secretary of State

Research-development-innovation, SMEs

Policies of research and innovation, synergies with small business. Obtaining Romania's host country status of implementing the Extreme Light Infrastructure (ELI) project and integrating Romania into

Center for Surface Science and NanoTechnology, University POLITEHNICA of Bucharest, Splaiul

ENIAC (European Nanoelectronics Initiative)

Ministry of Education, Research, Youth and Sport; National Authority for Scientific Research,

Founder and management of Center for Surface Science and NanoTechnology

Independentei nr. 313, sector 6, Bucharest 060042, ROMANIA

Mendeleev Str. 21-25, Bucharest 010362, ROMANIA

Government administration

October 2009 - onwards

Professor

Main activities and responsibilities

Research and teaching. Most classes offered to master syllabus students in the field of micro- and nano-materials and nanoscience. Research is focused on the field of materials science and nanotechnology

Name and address of employer

University POLITEHNICA of Bucharest, Splaiul Independentei nr. 313, sector 6, Bucharest 060042, ROMANIA

Type of business or sector

Research and education

Dates

December 1999 - April 2010

Occupation or position held

Visiting Scientist/Professor

Main activities and responsibilities

Research focused on ultrahigh vacuum atomic force microscopy and scanning tunneling microscopy (UHV-AFM-STM) experiments and nano-tribology and nano-fabrication issues on metals and semiconductor materials.

Name and address of employer

Materials Sciences Division, Lawrence Berkeley National Laboratory, University of California - Berkeley; 1 Cyclotron Road, Berkeley, CA 94720, USA

Type of business or sector

Research

Dates

December 1999 - June 2009

Occupation or position held Main activities and responsibilities

Chief Executive Officer and President

Proposed and implemented a new method and new equipment for defects detection, based on emission spectroscopy, aiming to detection, localization and identification of electronic defects on Flat Panel Displays, Printed Circuit Boards, and semiconductor devices Research involves micro- and nanometric defect detection, identification, characterization and repair for applications specific to semiconductor devices and flat panel display industry. Nine international patents were rewarded and additional five patent applications are submitted on these topics. Built prototype machine and production-type equipment for the market, bringing the corporation to over \$30,000,000 valuation.

Name and address of employer

Marena Systems Corporation and Candescent Technologies Corporation, 3563 Investment Blvd. #6, Hayward, CA 94545, USA

Type of business or sector

Business and research

Dates

January 1997 - November 1999

Occupation or position held

Postdoc Fellow

Main activities and responsibilities

Research/development work involved ultrahigh vacuum surface science techniques, e.g., AFM, STM, AES, LEED, SAM, SEM, SIMS, ESCA, sputtering as well as air and/or controlled humidity atmosphere investigations using the SPFM technique developed in our lab. Research was oriented toward aspects of friction, stiction, and wear at the atomic scale, MEMS failure analysis, nano-fabrication and electronic transport measurements through nanometer-size contacts, on semiconductors, metals and insulators.

Name and address of employer

Materials Sciences Division, Lawrence Berkeley National Laboratory, University of California – Berkeley; 1 Cyclotron Road, Berkeley, CA 94720, USA

Type of business or sector

Research

Dates

January 1995 - December 1996

Occupation or position held

Postdoctoral Research Associate

Main activities and responsibilities

Designed and built an unique UHV system for ideal atomic contact experiments. The unique systems is a combined AFM-STM-FIM, the design and implementation involving DSP electronics, fine mechanics, laser and optical interferometric system, I-V converter, etc.

Nano-tribology, nano-contacts, and nano-indentation experiments were the core of the research. Research/development work involved ultrahigh vacuum surface science techniques, e.g., AFM, STM, FIM, AES, LEED, SEM, XPS, TPD, SIMS, sputtering.

Name and address of employer

Laboratory of Surface Science and Technology, Sawyer Research Center, University of Maine, Orono, ME 04469, USA

Type of business or sector

Research and teaching

Dates

April 1994 - December 1994

Occupation or position held

Postdoc Research Scientist

Main activities and responsibilities

Research/development work oriented toward semiconductors and nano-devices, using STM, CVD, STM-CVD, AES, LEED, SEM, techniques. Achievements: Si(111) substrates and crystalline nano-particles deposition from solutions, and controlled deposition, location and size of Au dots by field-induced transfer of tip material, obtaining metallic nano-wires through STM-electron-stimulated decomposition of organometallic compounds, observation of Coulomb blockade and Coulomb staircase electronic transport, at room temperature, in a W-tip_vacuum gap_Au-dot_Si(111)-substrate configuration, etc.

Name and address of employer

Type of business or sector

Technical University of Munich, Boltzmannstrasse 15, 85748 Garching bei München, Germany

or Research and teaching

Dates

February 1991 - March 1994

Occupation or position held

PhD Research Fellow

Main activities and responsibilities

Designed and built the first UHV-STM system for Technical University of Munich.

Research/development work oriented toward nano-structuring and surface science, using STM, CVD, AES, LEED, SAM, SEM, RF sputtering techniques. The research projects involved a large class of materials: light-emitting porous silicon films, c-Si (111), c-Si(100), a-Si:H(P)/c-Si heterojunctions, superconductor films (YBa2Cu3O7-x) deposited onto different substrates (MgO, Si, GaAs), graphite, SiC nanoparticles deposited onto Si substrate, W/sapphire films, CVD-TiN films, Diamond CVD-deposited films.

Name and address of employer

Type of business or sector

Technical University of Munich, Boltzmannstrasse 15, 85748 Garching bei München, Germany

Research and teaching

ess or sector

Dates

October 1987 - September 1990

Occupation or position held

Assistant Professor

Main activities and responsibilities

Research/development work oriented toward electronic transport and photoconductivity in semiconductors, e.g. Si, GaAs. CdS, CdSe, PbS, as well as optical-charge spectroscopy and holography.

Name and address of employer

Faculty of Physics, University of Bucharest, , University of Bucharest, 405 Atomistilor Str, PO Box MG-11, Bucharest-Magurele 077125, Romania

Type of business or sector

Research and teaching

Dates

September 1983 - September 1987

Occupation or position held

Research Scientist

Main activities and responsibilities

Research/development work oriented toward IR & visible detectors, crystalline and organic semiconductors, e.g., PbS, InAs, GaAs, CdSe, CdS, chemical and e-beam depositions.

Name and address of employer

Institute of Physics and Technology of Materials, Str. Atomistilor nr. 105 bis, MAGURELE, Ilfov, Romania. Romania

Type of business or sector

Research

Education and training

Dates

January 1997- November 1999

Title of qualification awarded
Principal subjects/occupational skills
covered

Postdoc Fellow

Research/development work involved ultrahigh vacuum surface science techniques, e.g., AFM, STM, AES, LEED, SAM, SEM, SIMS, ESCA, sputtering as well as air and/or controlled humidity atmosphere investigations using the SPFM technique developed in our lab. Research was oriented toward aspects of friction, stiction, and wear at the atomic scale, MEMS failure analysis, nano-fabrication and electronic transport measurements through nanometer-size contacts, on semiconductors, metals and insulators.

Name and type of organization providing education and training

Materials Sciences Division, Lawrence Berkeley National Laboratory, University of California – Berkeley; 1 Cyclotron Road, Berkeley, CA 94720, USA

Dates

January 1995 - December 1996

Title of qualification awarded

Postdoctoral Research Associate

Principal subjects/occupational skills covered

Designed and built an unique UHV system for ideal atomic contact experiments. The unique systems is a combined AFM-STM-FIM, the design and implementation involving DSP electronics, fine mechanics, laser and optical interferometric system, I-V converter, etc.

Nano-tribology, nano-contacts, and nano-indentation experiments were the core of the research. Research/development work involved ultrahigh vacuum surface science techniques, e.g., AFM, STM, FIM, AES, LEED, SEM, XPS, TPD, SIMS, sputtering.

Name and type of organization providing education and training

Laboratory of Surface Science and Technology, Sawyer Research Center, University of Maine, Orono, ME 04469, USA

Dates

covered

April 1994 - December 1994

Title of qualification awarded Principal subjects/occupational skills Postdoc Research Scientist

Research/development work oriented toward semiconductors and nano-devices, using STM, CVD, STM-CVD, AES, LEED, SEM, techniques. Achievements: Si(111) substrates and crystalline nano-particles deposition from solutions, and controlled deposition, location and size of Au dots by field-induced transfer of tip material, obtaining metallic nano-wires through STM-electron-stimulated decomposition of organometallic compounds, observation of Coulomb blockade and Coulomb staircase electronic transport, at room temperature, in a W-tip_vacuum gap_Au-dot_Si(111)-substrate configuration, etc.

Name and type of organization providing education and training

Technical University of Munich, Boltzmannstrasse 15, 85748 Garching bei München, Germany

Dates

February 1991 - March 1994

Title of qualification awarded

PhD in Physics (Dr.rer.nat.)

Principal subjects/occupational skills covered

Thesis: "Scanning Tunneling Microscopy Studies of Light-Emitting Porous Silicon and Construction of a Special-Purpose Tunneling Microscope", Advisers: Prof. Dr. R. J. Behm and Prof. Dr. Frederick Koch Designed and built the first UHV-STM system for Technical University of Munich.

Research/development work oriented toward nano-structuring and surface science, using STM, CVD, AES, LEED, SAM, SEM, RF sputtering techniques. The research projects involved a large class of materials: light-emitting porous silicon films, c-Si (111), c-Si(100), a-Si:H(P)/c-Si heterojunctions, superconductor films (YBa2Cu3O7-x) deposited onto different substrates (MgO, Si, GaAs), graphite, SiC nanoparticles deposited onto Si substrate, W/sapphire films, CVD-TiN films, Diamond CVD-deposited films.

Name and type of organization providing education and training

Technical University of Munich, Boltzmannstrasse 15, 85748 Garching bei München, Germany

ates

September 1982 - July 1983

Title of qualification awarded

M.Sc. in Physics

Principal subjects/occupational skills

Physics of Organic Semiconductors

Name and type of organization providing education and training

Faculty of Physics, University of Bucharest, , University of Bucharest, 405 Atomistilor Str, PO Box MG-11, Bucharest-Māgurele 077125, Romania

Level in national or international classification

Top student over all Romanian universities, Physics Faculties/Departments; "Summa cum laude"

Dates

September 1978 - July 1982

Title of qualification awarded

B.Sc. in Physics

Principal subjects/occupational skills

Physics

covered

Name and type of organization providing education and training

Level in national or international classification

Faculty of Physics, University of Bucharest, , University of Bucharest, 405 Atomistilor Str, PO Box MG-11, Bucharest-Māgurele 077125, Romania

Top student over all Romanian universities, Physics Faculties/Departments;

"Summa cum laude"

Personal skills and competences

Mother tongue(s)

ROMANIAN

Other language(s)
Self-assessment
European level (*)

ENGLISH GERMAN

	Understanding				Speaking				Writing	
	Listening		Reading		Spoken interaction		Spoken production			
C2	Proficient user	C2	Proficient user	C2	Proficient user	C2	Proficient user	C2	Proficient user	
C2	Proficient user	C1	Proficient user	C1	Proficient user	C2	Proficient user	C2	Proficient user	

(*) Common European Framework of Reference for Languages

Artistic skills and competences

- four years studies in arts, e.g., painting, sculpturing, history of arts, etc.
- good team building and good communications skills
- capability of joining multicultural environments, build during my carrier experience

Other skills and competences

- experience in project management
- experience in educational management
- experience in implementing processes of evaluation and monitoring

Driving license

Driving license, B category

Additional information

- "Award in appreciation of the contribution to the development of the Romanian physics science", LEGAL POINT 2019
- VicePresident of American-Romanian Academy of Arts and Sciences, USA, 2009-2017
- Award for Forging the Limits and bringing the ELI project to the country ", MEDIAFAX, 2013.
- Personality of the Year 2011 for a European Romania, EUROLINK, 2011
- Award for Excellence in Physiscs/Chemistry, American Romanian Academy 2010, USA
- "Doctor Honoris Causa", University of Pitesti, Romania, January 2009
- Award of American Romanian Academy, 2009, USA.
- Honorary Citizen of Arges County, 2008
- Award of Romanian Academy, Section Physics, 1996, Romania
- D.A.A.D. fellow, 1991-1994, Germany
- Award of Ministry of Education, 1983, Romania

Annexes

Per request:

LIST OF INTERNATIONAL PATENTS LIST OF PUBLICATIONS

12.07.2023

